

FEATURES

- Single-Ended to Differential Conversion
- Low Noise: 1.4nV/ $\sqrt{\text{Hz}}$
- 20 μV_{RMS} Total Wideband Noise in Filter with 2MHz f_c
- Dynamic Range: 104dB SNR at $\pm 5\text{V}$
- Total Supply Voltage: 2.7V to 12V
- Rail-to-Rail Outputs
- DC Accurate: Op Amp V_{OS} 0.5mV (Typ)
- Trimmed Bandwidth for Accurate Filters
- No External Clock Required
- MSOP-8 Surface Mount Package

APPLICATIONS

- Low Noise, High Speed Filters to 5MHz
- Low Noise Differential Circuits
- Communication Channel or Roofing Filters
- Antialias or Reconstruction Filtering
- Video Signal Processing
- Single-Ended to Differential Conversion

DESCRIPTION

The LT[®]1567 is an analog building block optimized for very low noise high frequency filter applications. It contains two wideband rail-to-rail operational amplifiers, one of them internally configured as a unity-gain inverter. With the addition of a few passive components, the LT1567 becomes a flexible second order filter section with cutoff frequency (f_c) up to 5MHz, ideal for antialiasing or for channel filtering in high speed data communications systems. A spreadsheet-based design tool is available at www.linear.com for designing lowpass and bandpass filters using the LT1567.

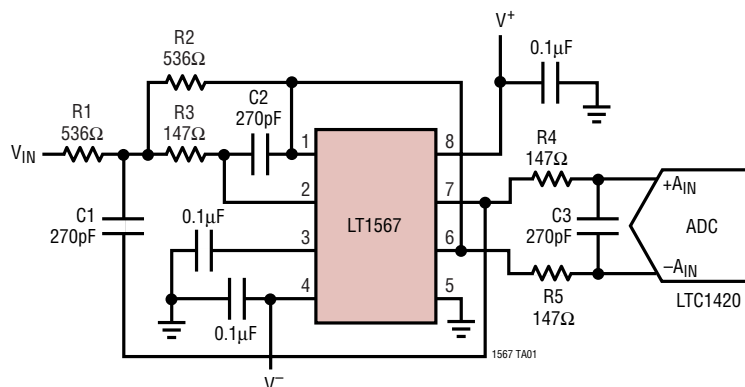
In addition to low noise and high speed, the LT1567 features single-ended to differential conversion for direct driving of high speed differential input A/D converters. The LT1567 operates from a total power supply voltage of 2.7V to 12V and supports signal-to-noise ratios above 100dB.

The LT1567 is available in an 8-lead MSOP package.

LT, LTC, LT and LTM are registered trademarks of Linear Technology Corporation. All other trademarks are the property of their respective owners.

TYPICAL APPLICATION

2MHz 3-Pole Antialias Filter with Single-Ended to Differential Conversion



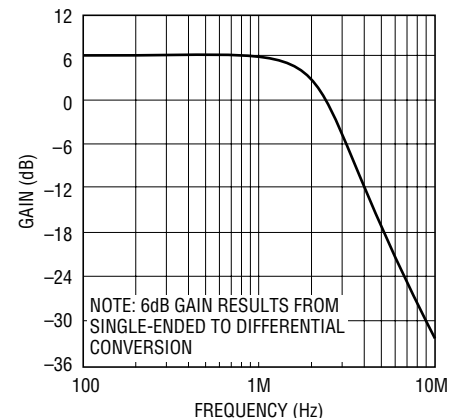
96dB DIFFERENTIAL SNR WITH 3V TOTAL SUPPLY

$$\text{GAIN} = \frac{R_2}{R_1} \leq \frac{2.5\text{MHz}}{f_{-3\text{dB}}}$$

$$R_3 = R_4 = R_5, C_1 = C_2 = C_3$$

$$f_{-3\text{dB}} = \frac{1.82}{2\pi R_2 C_2} = \frac{1}{4\pi R_3 C_3}; f_{-3\text{dB}} \leq 2.5\text{MHz}$$

Frequency Response



1567 TA01a

ABSOLUTE MAXIMUM RATINGS

(Note 1)

Total Supply Voltage (V ⁺ to V ⁻)	12.6V
Input Current (Note 2)	±25mA
Operating Temperature Range (Note 3)	
LT1567C	-40°C to 85°C
LT1567I	-40°C to 85°C
Specified Temperature Range (Note 4)	
LT1567C	-40°C to 85°C
LT1567I	-40°C to 85°C
Storage Temperature Range	-65°C to 150°C
Lead Temperature (Soldering, 10 sec)	300°C

PACKAGE/ORDER INFORMATION

	ORDER PART NUMBER
	LT1567CMS8 LT1567IMS8
	MS8 PART MARKING
	LTWH LTWJ
Order Options Tape and Reel: Add #TR Lead Free: Add #PBF Lead Free Tape and Reel: Add #TRPBF Lead Free Part Marking: http://www.linear.com/leadfree/	

Consult LTC Marketing for parts specified with wider operating temperature ranges.

ELECTRICAL CHARACTERISTICS

The ● denotes the specifications that apply over the full operating temperature range (Note 4), otherwise specifications and typical values are at T_A = 25°C. V_S = ±2.5V, R_L = 1K, V_{OUT} = 0 on both amplifiers unless otherwise noted.

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Total Supply Voltage		2.7		12	V
Supply Current	V _S = ±1.5V	●	8.5	15	mA
	V _S = ±2.5V	●	9	16	mA
	V _S = ±5V	●	11	19	mA
OA Output Positive Voltage Swing	V _S = ±1.5V, R _L = 1k	●	1.30	1.45	V
	V _S = ±2.5V, R _L = 1k	●	2.20	2.45	V
	V _S = ±2.5V, R _L = 100	●	1.90	2.25	V
	V _S = ±5V, R _L = 1k	●	4.70	4.90	V
OA Output Negative Voltage Swing	V _S = ±1.5V, R _L = 1k	●	-1.30	-1.45	V
	V _S = ±2.5V, R _L = 1k	●	-2.20	-2.45	V
	V _S = ±2.5V, R _L = 100	●	-2.00	-2.30	V
	V _S = ±5V, R _L = 1k	●	-4.70	-4.90	V
INV Output Positive Voltage Swing	V _S = ±1.5V, R _L = 1k	●	1.30	1.40	V
	V _S = ±2.5V, R _L = 1k	●	2.20	2.50	V
	V _S = ±2.5V, R _L = 100 (LT1567I Only, Note 5)	●	1.80	2.00	V
	V _S = ±5V, R _L = 1k	●	4.60	4.80	V
INV Output Negative Voltage Swing	V _S = ±1.5V, R _L = 1k	●	-1.30	-1.40	V
	V _S = ±2.5V, R _L = 1k	●	-2.20	-2.40	V
	V _S = ±2.5V, R _L = 100 (LT1567I Only, Note 5)	●	-1.80	-2.00	V
	V _S = ±5V, R _L = 1k	●	-4.50	-4.80	V
Common Mode Input Voltage Range (DC BIAS, Pin 5) (See Pin Functions)	V _S = ±1.5V, CMRR ≥ 40dB (Note 6)	●	-0.5	0.5	V
	V _S = ±5V, CMRR ≥ 40dB (Note 6)	●	-3.8	3.5	V
DC Common Mode Rejection Ratio (CMRR)	V _S = ±1.5V, DC BIAS = -0.25V to 0.25V	●	80		dB
	V _S = ±5V, DC BIAS = -2.5V to 2.5V	●	65	90	dB
DC Power Supply Rejection Ratio (PSRR)	V _S = ±1.5V to ±5V, DC BIAS = 0V	●	80	100	dB
OA Input Offset Voltage		●	0.5	3	mV
INV Output Offset Voltage		●	5	9	mV

ELECTRICAL CHARACTERISTICS

The ● denotes the specifications that apply over the full operating temperature range (Note 4), otherwise specifications and typical values are at $T_A = 25^\circ\text{C}$. $V_S = \pm 2.5\text{V}$, $R_L = 1\text{k}$, $V_{OUT} = 0$ on both amplifiers unless otherwise noted.

PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
OA Input Bias Current		●		3	10	μA
DC BIAS Input Bias Current		●		6	15	μA
OA DC Open-Loop Gain	$V_S = \pm 1.5\text{V}$, $R_L = 1\text{k}$, $V_O = -1\text{V}$ to 1V	●	7.5	55		V/mV
	$V_S = \pm 2.5\text{V}$, $R_L = 1\text{k}$, $V_O = -2\text{V}$ to 2V	●	10	60		V/mV
	$V_S = \pm 2.5\text{V}$, $R_L = 100$, $V_O = -1.5\text{V}$ to 1.5V	●	1.2	7.0		V/mV
	$V_S = \pm 5\text{V}$, $R_L = 1\text{k}$, $V_O = -4\text{V}$ to 4V	●	10	80		V/mV
INV DC Gain	$V_S = \pm 1.5\text{V}$, $R_L = 1\text{k}$, $V_{IN} = -1\text{V}$ to 1V	●	0.97		1.04	V/V
	$V_S = \pm 2.5\text{V}$, $R_L = 1\text{k}$, $V_{IN} = -2\text{V}$ to 2V	●	0.97		1.04	V/V
	$V_S = \pm 2.5\text{V}$, $R_L = 100$, $V_{IN} = -1.5\text{V}$ to 1.5V	●	0.97		1.04	V/V
	$V_S = \pm 5\text{V}$, $R_L = 1\text{k}$, $V_{IN} = -4\text{V}$ to 4V	●	0.97		1.04	V/V
INV DC Input Resistance	$V_S = \pm 2.5\text{V}$, $R_L = 1\text{k}$, $V_{IN} = -2\text{V}$ to 2V	●	450	600	750	Ω
OA Gain Bandwidth Product	Measured at 2MHz, $V_S = \pm 1.5\text{V}$	●	100	180		MHz
	Measured at 2MHz, $V_S = \pm 2.5\text{V}$	●	110	185		MHz
	Measured at 2MHz, $V_S = \pm 5\text{V}$	●	120	190		MHz
INV Bandwidth	-3dB			85		MHz
INV AC Gain	Measured at 2MHz	●	0.96	1.0	1.05	V/V
OA Slew Rate	$V_S = \pm 5\text{V}$			55		$\text{V}/\mu\text{s}$
INV Slew Rate	$V_S = \pm 5\text{V}$			90		$\text{V}/\mu\text{s}$
OA Input Voltage Noise Density (Note 7)	$f = 100\text{kHz}$			1.4		$\text{nV}/\sqrt{\text{Hz}}$
OA Input Current Noise Density	$f = 100\text{kHz}$			1.0		$\text{pA}/\sqrt{\text{Hz}}$
Wideband Output Noise for a Second Order Filter (Figure 1)	$f_C = 2\text{MHz}$, BW = 4MHz (Note 8)			20		μV_{RMS}
	$f_C = 5\text{MHz}$, BW = 10MHz (Note 8)			30		μV_{RMS}
Total Harmonic Distortion (THD) for a Second Order Filter (Figure 1)	$f = 1\text{MHz}$, $f_C = 2\text{MHz}$, $V_{OUT} = 1\text{V}_{\text{RMS}}$			-88		dB
	$f = 2.5\text{MHz}$, $f_C = 5\text{MHz}$, $V_{OUT} = 1\text{V}_{\text{RMS}}$			-70		dB
Output Short-Circuit Current (Note 9)		●	8	50		mA
OA Output Impedance	$f = 100\text{kHz}$, OA Connected as Unity-Gain Inverter			0.03		Ω
INV Output Impedance	$f = 100\text{kHz}$			0.7		Ω

Note 1: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

Note 2: The inputs of each op amp are protected by back-to-back diodes and diodes to each supply. If either input exceeds the supply or the differential input voltage exceeds 1.4V, the input current should be limited to less than 25mA.

Note 3: The LT1567C and LT1567I are guaranteed functional over the operating temperature range -40°C to 85°C .

Note 4: The LT1567C is guaranteed to meet specified performance from 0°C to 70°C . The LT1567C is designed, characterized and expected to meet specified performance from -40°C to 85°C but not tested or QA sampled at these temperatures. The LT1567I is guaranteed to meet specified performance from -40°C to 85°C .

Note 5: With INVIN pin driven to $\pm 2\text{V}$.

Note 6: This parameter is not 100% tested.

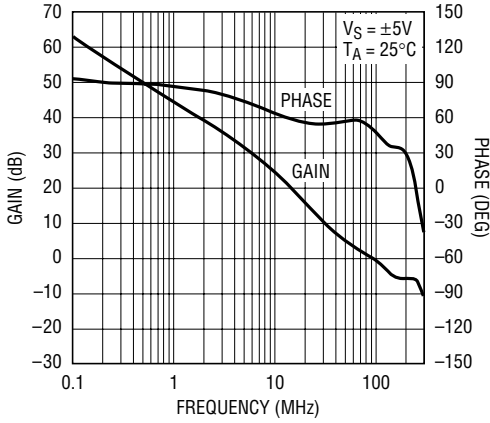
Note 7: The input referred voltage noise density of the unity gain inverter is $5.6\text{nV}/\sqrt{\text{Hz}}$ which includes the noise of the gain setting resistors.

Note 8: For $f_C = 2\text{MHz}$, $C_1 = C_2 = 180\text{pF}$, $R_1 = R_2 = 604\Omega$, $R_3 = 316\Omega$ and for $f_C = 5\text{MHz}$, $C_1 = C_2 = 180\text{pF}$, $R_1 = R_2 = 232\Omega$, $R_3 = 130\Omega$. BW is the bandwidth of the noise measurement (Figure 1 circuit).

Note 9: Under direct short circuit conditions, with $T_A < 25^\circ\text{C}$ the output current is reduced.

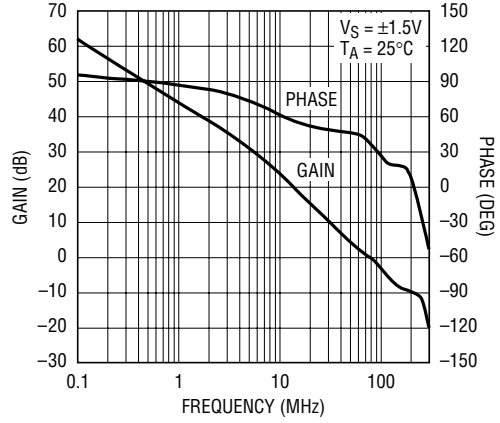
TYPICAL PERFORMANCE CHARACTERISTICS

OA Open-Loop Gain and Phase vs Frequency



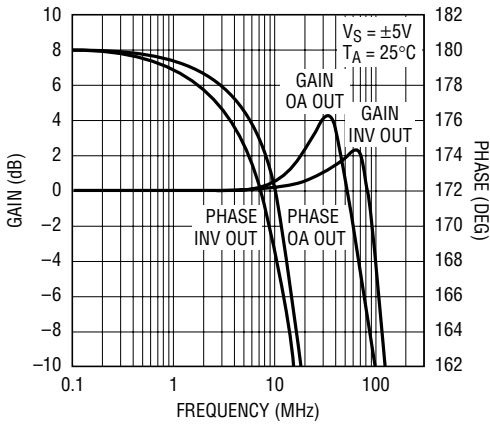
1567 G01

OA Open-Loop Gain and Phase vs Frequency



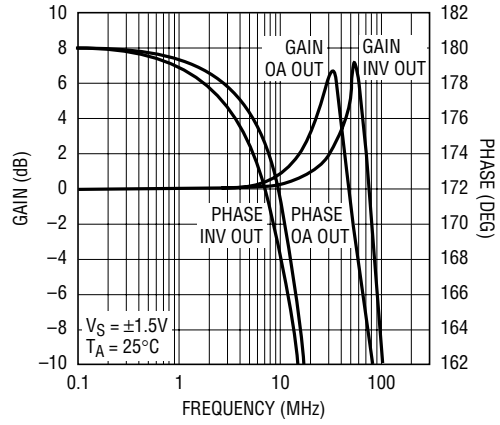
1567 G02

Closed-Loop Gain and Phase of OA and INV vs Frequency (AV = -1)



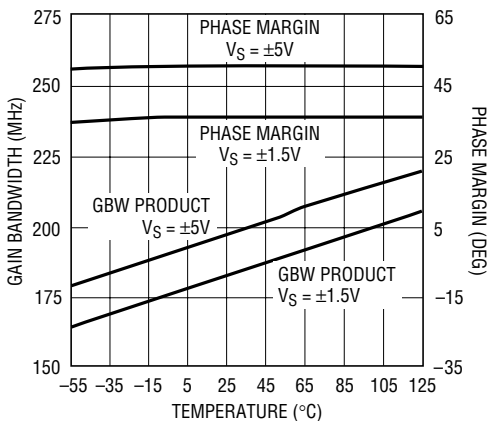
1567 G03

Closed-Loop Gain and Phase of OA and INV vs Frequency (AV = -1)



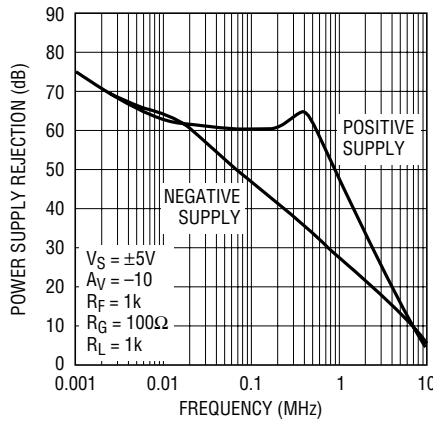
1567 G15

OA Gain Bandwidth Product and Phase Margin vs Temperature



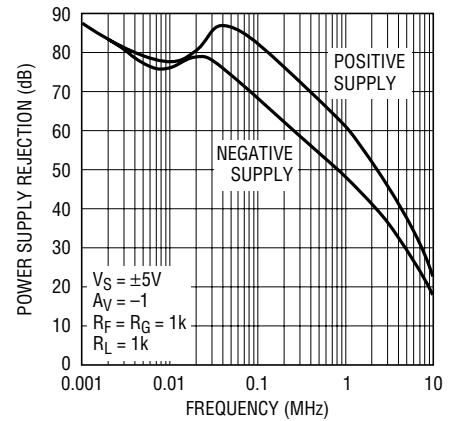
1567 G14

PSRR of OA vs Frequency



1567 G04

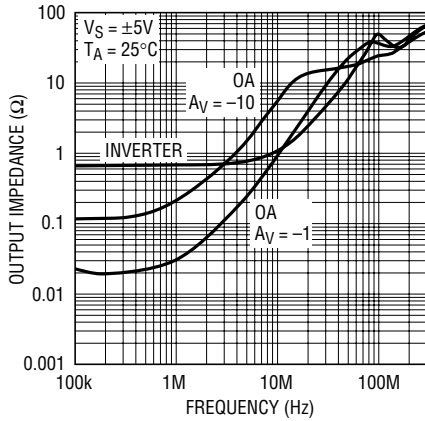
PSRR of OA or INV vs Frequency



1567 G05

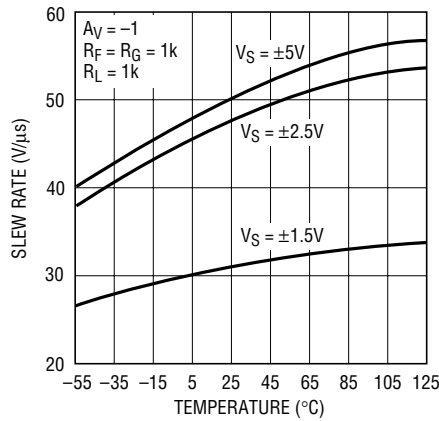
TYPICAL PERFORMANCE CHARACTERISTICS

Output Impedance vs Frequency



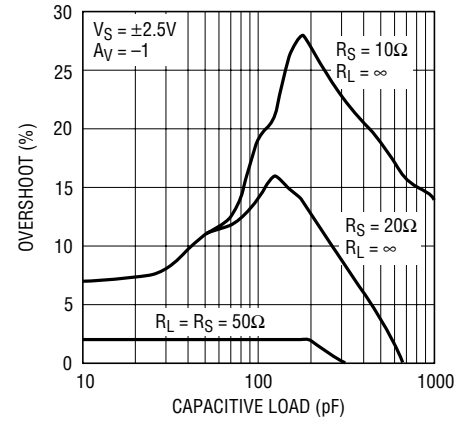
1567 G06

OA Rising Slew Rate vs Temperature



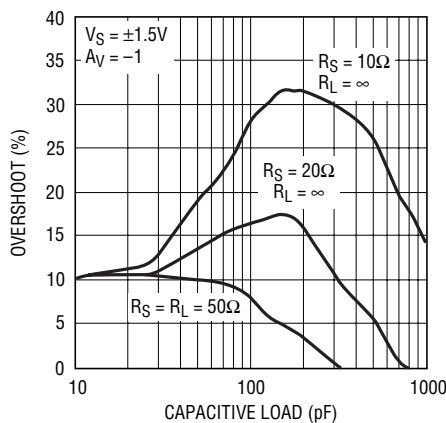
1567 G07

Output Overshoot vs Series Resistor and Capacitive Load



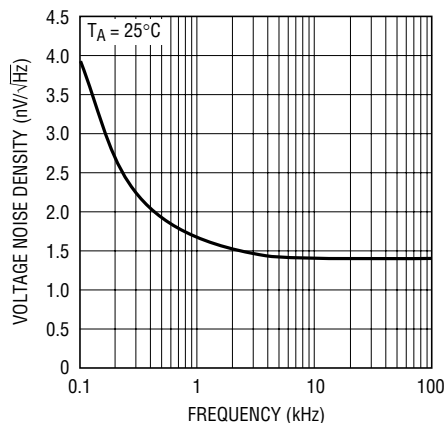
1567 G08

Output Overshoot vs Series Resistor and Capacitive Load



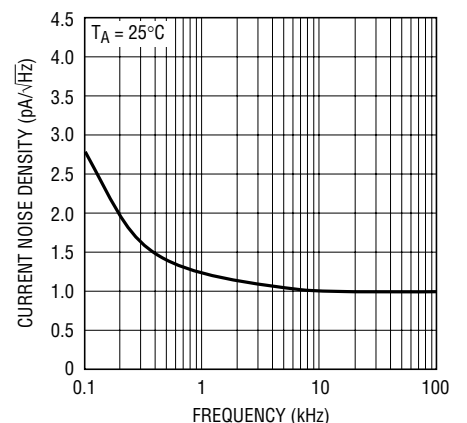
1567 G09

Input Voltage Noise Density of OA vs Frequency



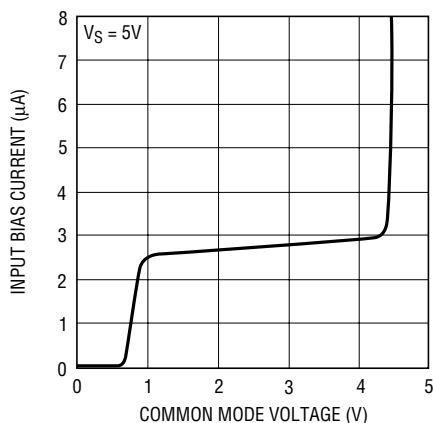
1567 G10

Input Current Noise Density of OA vs Frequency



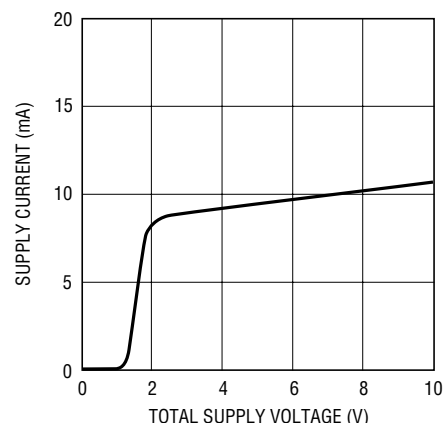
1567 G11

Input Bias Current of OA vs Common Mode Voltage



1567 G12

Supply Current vs Supply Voltage



1567 G13

PIN FUNCTIONS

OAOUT (Pin 1): Output of the Uncommitted Op Amp (OA). As with most wideband op amps, it is important to avoid connecting heavy capacitive loads (above about 10pF) directly to this output. Such loads will impair AC stability and should be isolated from the output through series resistance.

OAIN (Pin 2): Inverting or “–” Input of the Uncommitted Op Amp (OA) in the LT1567. The noninverting or “+” input of this amplifier is shared with that of the INV amplifier and accessed via the DC BIAS and BYPASS pins. The OA amplifier is optimized for minimal wideband noise.

BYPASS (Pin 3): AC Ground Bypass. A decoupling capacitor, typically 0.1 μ F, from this pin to a printed circuit ground plane must be used. Use the shortest possible wiring.

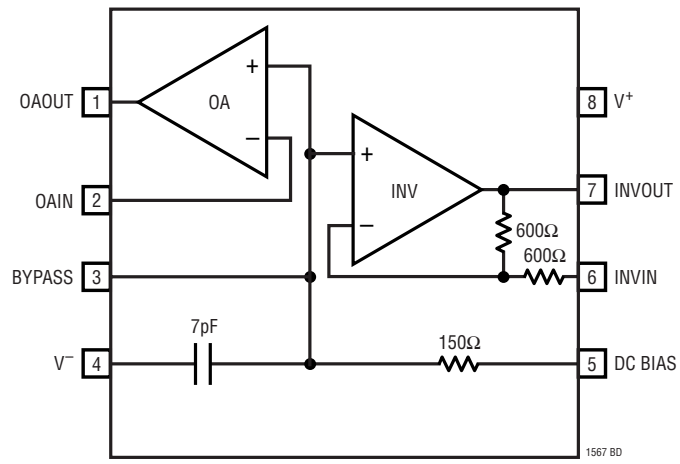
Power Supply Pins (Pins 4, 8): The V^- and V^+ pins should be bypassed with 0.1 μ F capacitors to an adequate analog ground plane using the shortest possible wiring. Electrically clean supplies and a low impedance ground are important to obtain the wide dynamic range and bandwidth available from the LT1567. Low noise linear power supplies are recommended. Switching supplies require special care because of the inevitable risk of their switching noise coupling into the signal path, reducing dynamic range.

DC BIAS (Pin 5): DC Biasing Input. Sets the DC voltage at the noninverting inputs of the two internal amplifiers; designed for use as a DC reference, not a signal input. The DC BIAS input includes a small series resistor, both to balance DC offsets in the presence of input bias currents and also to suppress the “Q” factor of possible parasitic high frequency resonant circuits introduced by wiring inductance. The reference voltage at the noninverting inputs of the two amplifiers is decoupled for very high frequencies with a small internal capacitor to the chip substrate, nominally 7pF. An external capacitor, typically 0.1 μ F, to a nearby ground plane must be added at Pin 3 (BYPASS) for a clean wideband DC reference biasing voltage.

INVIN (Pin 6): Unity-Gain Inverter Input. The “inverter” (INV) amplifier in the LT1567 is connected to internal resistors (nominally 600 Ω each) to form a closed-loop amplifier with a wideband voltage gain of nominally -1 . This amplifier is similar to the uncommitted op amp (OA) but is optimized for high frequency linearity.

INVOUT (Pin 7): Output of the INV or “Inverter” Amplifier, with a Nominal Gain of -1 from the INVIN Pin. As with most wideband op amps, it is important to avoid connecting heavy capacitive loads (above about 10pF) directly to this output. Such loads will impair AC stability and should be isolated from the output through series resistance.

BLOCK DIAGRAM



APPLICATIONS INFORMATION

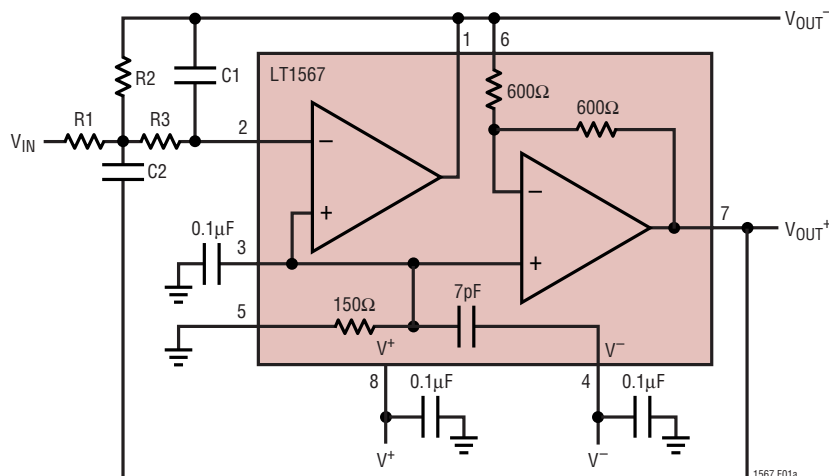
Functional Description

The LT1567 contains two low noise rail-to-rail output, wideband operational amplifiers, one of them connected internally as a unity-gain inverter. These two amplifiers can form a second order multiple feedback filter configuration (Figure 1) for megahertz signal frequencies, with exceptionally low total noise. The amplifier in the dedicated inverter (INV) is optimized for better high frequency linearity while the uncommitted operational amplifier (OA) is optimized for lower input noise voltage,

addressing the different sensitivities to these effects when used as a filter section. This combination produces a low noise filter with better distortion performance than would be possible with identical amplifiers.

LT1567 Free Design Software

A spreadsheet-based design tool is available at www.linear.com for designing lowpass and bandpass filters using the LT1567.



DESIGN EQUATIONS:

$$\text{GAIN} = 1 \text{ AND } f_c \leq 1\text{MHz} \left(\text{GAIN} = \frac{R_2}{R_1} \right)$$

f_c IS THE FILTER'S CUTOFF FREQUENCY

$$R_1 = R_2, C_1 = C_2, C_1 \leq \frac{1}{1000 \cdot f_c}$$

$$\text{BUTTERWORTH } R_2 = \frac{1}{4.44 \cdot C_1 \cdot f_c}$$

$$R_3 = \frac{R_2}{2}$$

$$\text{CHEBYSHEV } 0.25\text{dB RIPPLE } R_2 = \frac{1}{5.65 \cdot C_1 \cdot f_c}$$

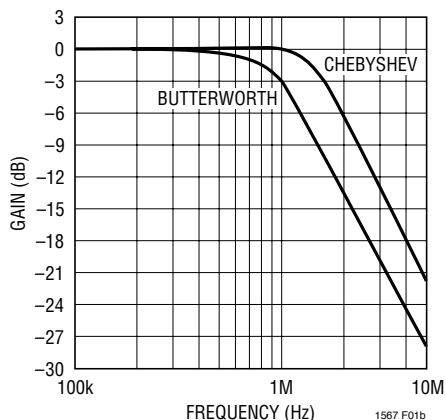
$$R_3 = \frac{R_2}{2.62}$$

$$f_0 = \frac{1}{2\pi\sqrt{R_2 R_3} C_2}$$

$$Q = \frac{\sqrt{R_2}}{R_3} \cdot \text{GAIN} + 1$$

$$\text{TRANSFER FUNCTION } H(s) = \frac{(2\pi f_0)^2}{s^2 + \frac{(2\pi f_0)}{Q} s + (2\pi f_0)^2}$$

Gain vs Frequency



GAIN IS MEASURED TO EITHER OUTPUT ALONE.
IF OUTPUT USED DIFFERENTIALLY, $V_{OUT+} - V_{OUT-} = 2 \times V_{IN}$

Figure 1. 2nd Order Lowpass Filter and Gain Response for $f_c = 1\text{MHz}$
(Butterworth: $C_1 = C_2 = 390\text{pF}$, $R_1 = R_2 = 576\Omega$, $R_3 = 280\Omega$
Chebyshev: $C_1 = C_2 = 390\text{pF}$, $R_1 = R_2 = 453\Omega$, $R_3 = 174\Omega$)

APPLICATIONS INFORMATION

The simple-to-use spreadsheet requires the user to define the desired corner (or center) frequency, the pass-band gain and a capacitor value for a choice of second or third order Chebyshev or Butterworth lowpass or second order bandpass filters.

The spreadsheet outputs the required external standard component values and provides a circuit diagram.

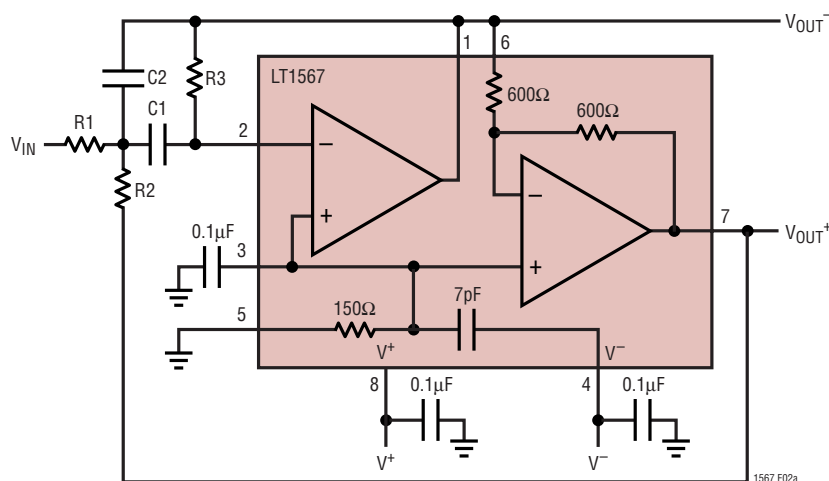
Signal Ground

Both operational amplifiers within the LT1567 are designed for inverting operation (constant common mode

input) and they share a single reference node on the chip. Two pins permit access to this node: DC BIAS and BYPASS. For a clean reference over a wide bandwidth, the normal procedure is to connect DC BIAS to a DC potential or ground and BYPASS to a decoupling capacitor that returns to a ground plane.

Differential Output Feature

The multiple feedback filter section of Figure 1 inherently includes two outputs of opposite signal polarity: a DC inverting output from the OA (Pin 1) and a DC noninverting

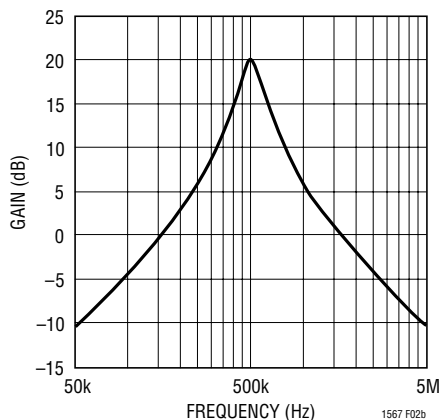


DESIGN EQUATIONS FOR $f_{CENTER} \leq 1\text{MHz}$
 f_{CENTER} IS THE FILTER'S CENTER FREQUENCY
 MAXIMUM $f_{CENTER} = 5\text{MHz}/\text{GAIN}$
 GN IS GAIN AT $f_{CENTER} = R3/R1$, $R2 = R3$, $C1 = C2$

$$f_{CENTER} = \frac{\sqrt{GN+1}}{2 \cdot \pi \cdot R2 \cdot C1} \quad -3\text{dB BANDWIDTH} = \frac{f_{CENTER}}{\sqrt{GN+1}}$$

$$C1 \leq \frac{\sqrt{GN+1}}{2500 \cdot f_C} \quad R3 = \frac{\sqrt{GN+1}}{2\pi \cdot C1 \cdot f_{CENTER}}$$

Gain vs Frequency



GAIN IS MEASURED TO EITHER OUTPUT ALONE.
 IF OUTPUT USED DIFFERENTIALLY, $V_{OUT+} - V_{OUT-} = 2 \times V_{IN}$

Figure 2. 2nd Order Bandpass Filter and Gain Response for $f_C = 500\text{kHz}$, Gain = 10 ($C1 = C2 = 1000\text{pF}$, $R2 = R3 = 1.05\text{k}$, $R1 = 105\Omega$)

APPLICATIONS INFORMATION

output from the INV block (Pin 7). These two outputs maintain equal gain and 180° phase shift over a wide frequency range. This feature permits choosing the signal polarity in single ended applications, and also performs single ended to differential conversion. The latter property is useful as an antialiasing filter to drive standard monolithic A/D converters having differential inputs, as illustrated on the first page of this data sheet.

Dealing with High Source Impedances

The voltage V_{IN} in Figure 1, on the left side of R1, is the signal voltage that the filter sees. If a voltage source with significant internal impedance drives the V_{IN} node in Figure 1, then the filter input V_{IN} may differ from the source's open-circuit output, and the difference can be complex, because the filter presents a complex impedance to V_{IN} . A rule of thumb is that a source impedance is negligibly "low" if it is much smaller than R1 at frequencies of interest. Otherwise, the source impedance (resistive or reactive) effectively adds to R1 and may change the signal frequency response compared to that with a low source impedance. If the source is resistive and predictable, then it may be possible to design for it by reducing R1. Unpredictable or nonresistive source impedances that are not much less than R1 should be buffered.

Construction and Instrumentation Cautions

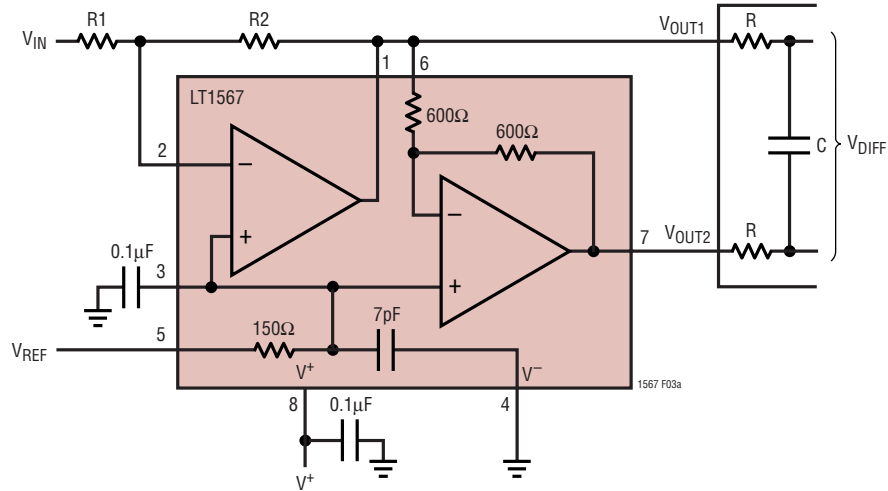
Electrically clean construction is important in applications seeking the full dynamic range and bandwidth of the LT1567. Using the shortest possible wiring or printed-circuit paths will minimize parasitic capacitance and inductance. High quality supply bypass capacitors of 0.1 μ F near the chip, connected to a ground plane, provide good decoupling from a clean, low inductance power source. But several inches of wire (i.e., a few microhenrys of inductance) from the power supplies, unless decoupled by substantial capacitance ($\geq 10\mu$ F) near the chip, can

cause a high Q LC resonance in the hundreds of kHz in the chip's supplies or ground reference. This may impair filter performance at those frequencies. In stringent filter applications, a compact, carefully laid out printed circuit board with good ground plane makes a difference in both stopband rejection and distortion. Finally, equipment to measure filter performance can itself introduce distortion or noise. Checking for these limits with a wire in place of the filter is a prudent routine procedure.

Low Noise Differential Circuits

The LT1567 is an optimum analog building for designing single supply differential circuits to process low level signals. Figure 3 shows a single ended to differential amplifier driving a 1st order differential RC filter. The differential output of Figure 3 is a function of input (V_{IN}) and the V_{REF} voltage on Pin 5. (The range of the V_{REF} voltage on Pin 5 in Figures 3, 4 and 5 is the common mode input voltage range parameter under Electrical Characteristics.) The graph of Figure 3 shows the differential signal-to-noise ratio for a gain of 2 and a gain of 10. Increasing the differential gain increases the differential signal-to-noise ratio. The equivalent input noise is equal to the output noise divided by the gain. For example, with a gain equal to 2 ($R_2 = R_1 = 200\Omega$) and a gain equal to 10 ($R_2 = 1k, R_1 = 200\Omega$), the equivalent input noise is 4.59nV/ $\sqrt{\text{Hz}}$ and 2.04nV/ $\sqrt{\text{Hz}}$ respectively. The V_{REF} voltage on Pin 5 can be set by a voltage divider or a reference voltage source. To maximize the unclipped LT1567 output swing, the DC output voltage should be set at $V^+/2$. However, if V_{INDC} (the input DC voltage) is within the range of V_{REF} , then V_{REF} can be equal to V_{INDC} . The input signal can also be AC coupled to the input resistor, R1, and V_{REF} set to the DC voltage of the circuit following the amplifier. For example, V_{REF} might be set to 1.2V to bias the input of an I and Q modulator used in broadband communication systems.

APPLICATIONS INFORMATION



$$V_{OUT1} = -\frac{R2}{R1} \cdot V_{IN} + \left(\frac{R2}{R1} + 1\right) \cdot V_{REF} \quad V_{OUT2} = -V_{OUT1} + 2 \cdot V_{REF}$$

$$V_{DIFF} = V_{OUT2} - V_{OUT1} = 2 \cdot \frac{R2}{R1} \cdot (V_{IN} - V_{REF}) \quad f_{-3dB} = \frac{1}{4\pi \cdot R \cdot C}$$

$$f_{\eta BW} \text{ IS THE NOISE BANDWIDTH} \quad f_{\eta BW} = \frac{1.57}{4\pi \cdot R \cdot C}$$

Differential Output Signal-to-Noise Ratio
(for a Sinewave Signal)

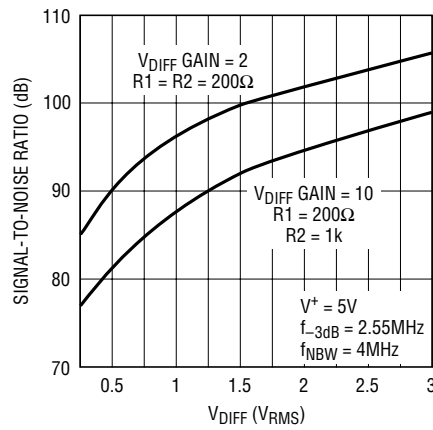


Figure 3. A Single Ended to Differential Amplifier

APPLICATIONS INFORMATION

Figure 4 shows an LT1567 single supply differential buffer driving a differential 1st order RC filter. The V_{REF} voltage is subject to the common mode (DC BIAS) limits in the spec table. Within this constraint, V_{REF} can be used to adjust the output common mode level, as noted in Figure 4. For example, in a single 5V power supply circuit, if the input common mode DC voltage is 1.1V and V_{REF} is 1.8V, then the output common mode DC voltage is 2.5V.

Figure 5 shows a low noise differential to single ended amplifier and 1st order lowpass filter. The input common mode rejection depends on the matching of resistors R1 and R3 and the LT1567 inverter gain tolerance (common mode rejection is at least 38dB up to 1MHz with 1% resistors and 5% inverter gain tolerance). The DC voltage at the amplifier's output (V_{OUT}) is V_{REF} .

Output Drive

The output of the LT1567 op amp (Pin 1) can typically provide at least $\pm 20\text{mA}$. The minimum resistive load to ground that Pin 1 or Pin 7 can drive depends on the feedback resistor and the peak output voltage. For example, the differential driver circuit in Figure 4 is operating with a single 5V supply, V_{REF} and V_{INDC} are equal to 2.5V and the peak AC signal (V_{INAC}) is 1V. If the outputs provide 1.66mA to the feedback resistors ($1\text{V}/604\Omega$), then 18.34mA is available to drive a resistive load. With the peak output voltage at 3.5V (2.5V DC plus 1V peak AC), the outputs can drive resistive loads of 191Ω or greater.

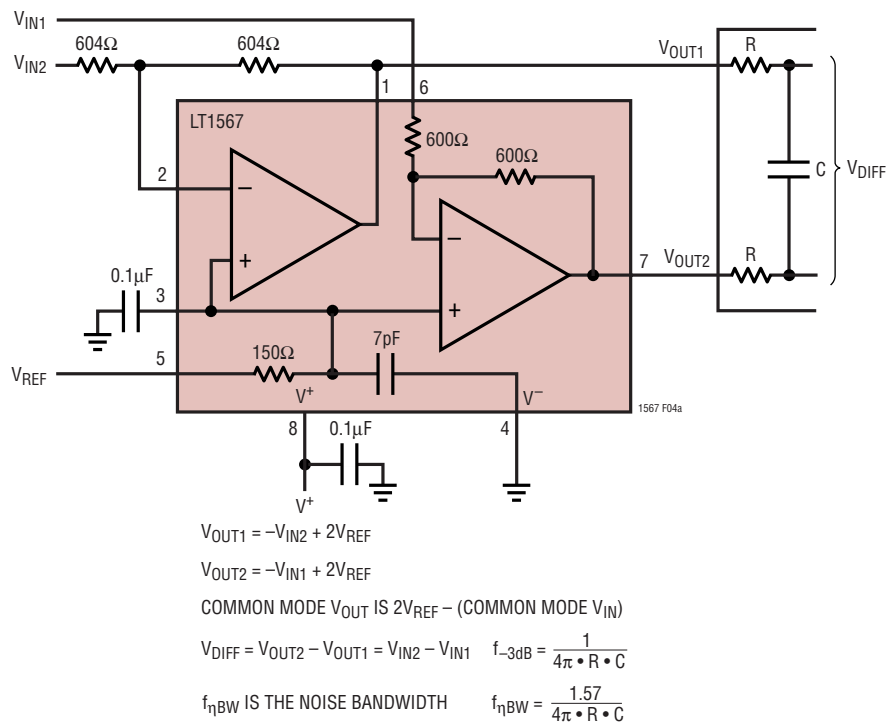
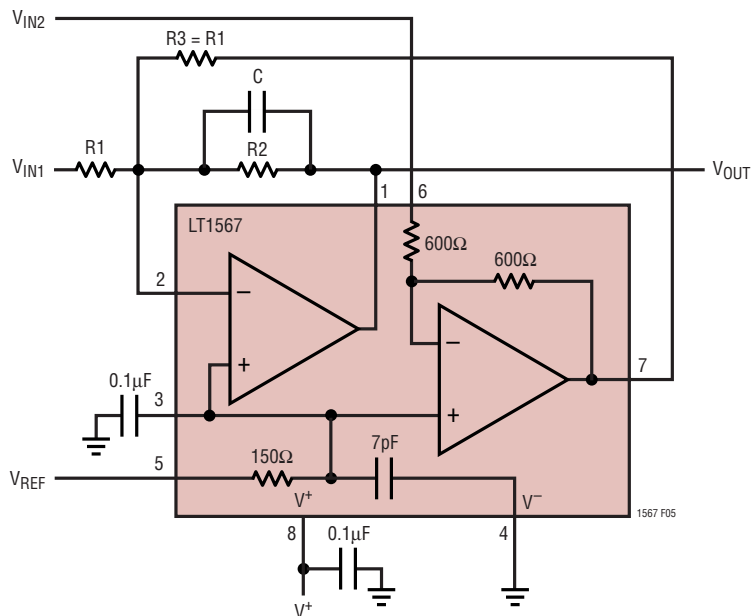


Figure 4. A Differential Buffer/Driver

APPLICATIONS INFORMATION



WITH R3 AND R1 EQUAL, $V_{OUT} = V_{REF} + \left(\frac{R2}{R1}\right) (V_{IN2} - V_{IN1})$

GAIN FROM $(V_{IN2} - V_{IN1})$ TO V_{OUT} IS $\left(\frac{R2}{R1}\right) f_{-3dB} = \frac{1}{2\pi \cdot R2 \cdot C}$

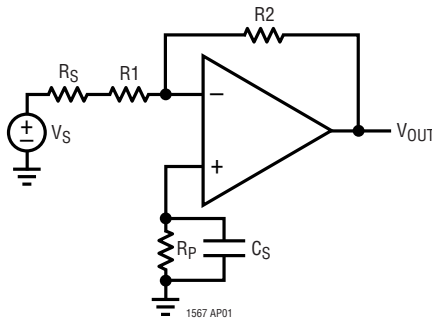
IF R1 = R3 = 604Ω, THEN

R2	GAIN	V _η , INPUT REFERRED NOISE (nV/√Hz)
604Ω	1	9.0
1.21k	2	8.4
2.43k	4	8.1

NOISE AT $V_{OUT} = GAIN \cdot V_{\eta} \cdot \sqrt{f_{\eta BW}}$; $f_{\eta BW} = 1.57 \cdot f_{-3dB}$

Figure 5. A Differential to Single Ended Amplifier/Filter

APPENDIX: OUTPUT NOISE OF AN OP AMP INVERTING AMPLIFIER



NOISE AT V_{OUT} IN $V_{RMS} = V_{ON}$ IN $V/\sqrt{Hz} \cdot \sqrt{f_{NBW}}$
 f_{NBW} = NOISE BANDWIDTH

$$V_{ON} = \sqrt{\left(\frac{R_2}{R_1 + R_S} + 1\right)^2 \cdot V_N^2 + \left(\frac{R_2}{R_1 + R_S}\right)^2 \cdot (V_{R1}^2 + V_{SN}^2) + V_{R2}^2 + (I_N \cdot R_2)^2}$$

IF V_{SN} AND $R_S = 0$
 THEN

$$V_{ON} = \sqrt{\left(\frac{R_2}{R_1} + 1\right)^2 \cdot V_N^2 + \left(\frac{R_2}{R_1}\right)^2 \cdot V_{R1}^2 + V_{R2}^2 + (I_N \cdot R_2)^2}$$

V_{ON} is the voltage noise density in V/\sqrt{Hz} at the inverter's output.

V_N is the op amp's voltage noise density in V/\sqrt{Hz} .

I_N is the op amp's current noise density in A/\sqrt{Hz} .

V_{SN} is the voltage noise density of the input voltage source V_S with source resistance R_S . (If V_{SN} is less than one-half the noise of resistor R_1 , then the calculation error when omitting V_{SN} is less than 4.3%.)

V_{R1} and V_{R2} is the voltage noise density of the thermal noise of resistors $(R_1 + R_S)$ and R_2 respectively. Resistor R_S is typically smaller than R_1 and is omitted from noise

calculations. The voltage noise density of the thermal noise of a resistor R is approximately $0.128\sqrt{RnV}/\sqrt{Hz}$ at $25^\circ C$.

The R_P resistor noise at the op amp's plus input is equal to $\sqrt{(kT/C_S)}$ and is omitted from noise calculations. (If $C_S = 0.1\mu F$, the R_P noise is $0.2\mu V_{RMS}$ at $25^\circ C$, $k = 1.38 \times 10^{-23}$ and $T = 273^\circ C + 25^\circ C$.)

The noise bandwidth (f_{NBW}) is greater than a circuit's $-3dB$ bandwidth. (For a 1st, 2nd or 3rd order Butterworth filter, f_{NBW} is 1.57x, 1.22x and 1.15x respectively the $-3dB$ bandwidth.)

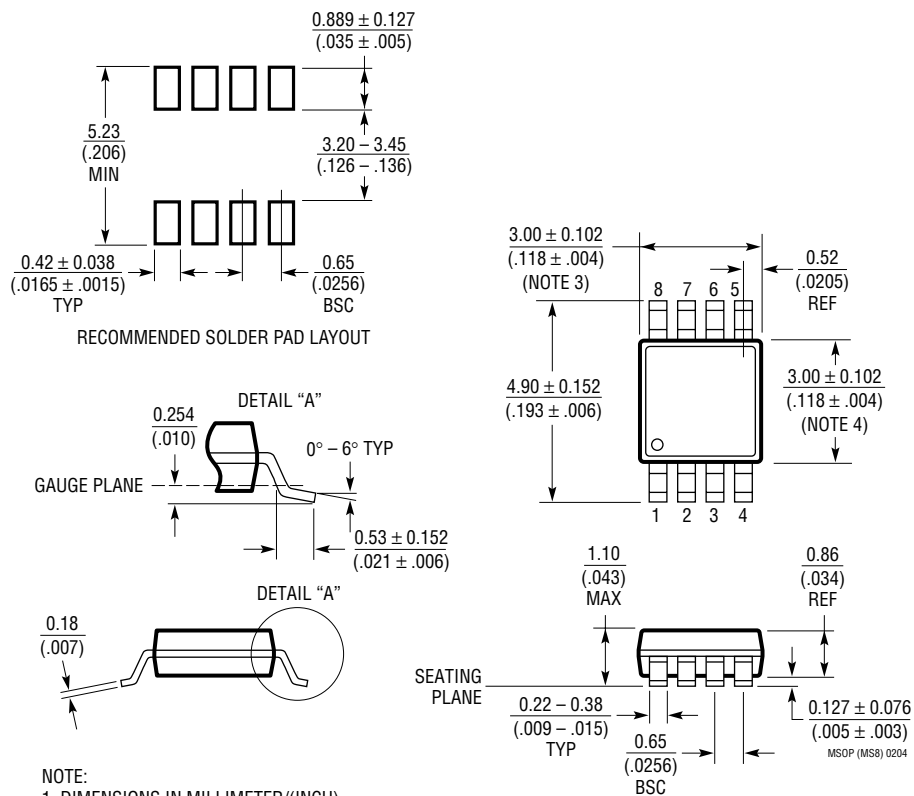
Example: Calculate V_{ON} , the voltage noise density of an LT1567 op amp inverter for $R_1 = R_2 = 604\Omega$. With $V_N = 1.4nV/\sqrt{Hz}$ and $I_N = 1pA/\sqrt{Hz}$.

$$V_{ON} = \sqrt{\left(\frac{604}{604} + 1\right)^2 \cdot (1.4 \cdot 10^{-9})^2 + \left(\frac{604}{604}\right)^2 \cdot (0.128 \cdot 10^{-9} \cdot \sqrt{604})^2 + (0.128 \cdot 10^{-9} \cdot \sqrt{604})^2 + (10^{-12} \cdot 604)^2}$$

$$V_{ON} = 5.29nV/\sqrt{Hz}$$

PACKAGE DESCRIPTION

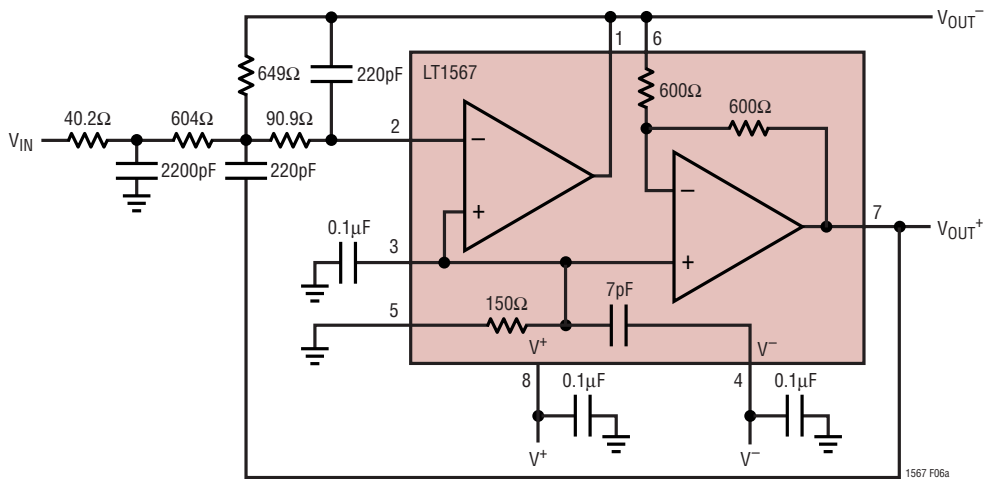
MS8 Package 8-Lead Plastic MSOP (Reference LTC DWG # 05-08-1660)



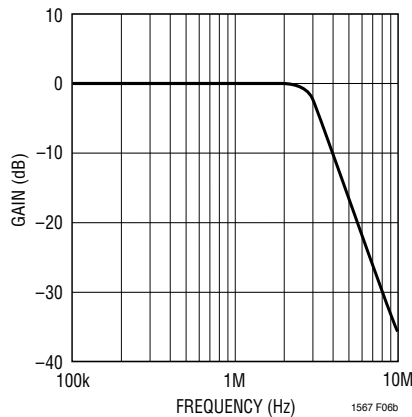
- NOTE:
1. DIMENSIONS IN MILLIMETER/(INCH)
 2. DRAWING NOT TO SCALE
 3. DIMENSION DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.152mm (.006") PER SIDE
 4. DIMENSION DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSIONS.
INTERLEAD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.152mm (.006") PER SIDE
 5. LEAD COPLANARITY (BOTTOM OF LEADS AFTER FORMING) SHALL BE 0.102mm (.004") MAX

TYPICAL APPLICATION

A 3rd Order Chebyshev 2.5MHz Lowpass Filter



Gain Response



GAIN IS MEASURED TO EITHER OUTPUT ALONE.
IF OUTPUT USED DIFFERENTIALLY, $V_{OUT+} - V_{OUT-} = 2 \times V_{IN}$

RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LTC [®] 1560-1	1MHz/500kHz Continuous Time, Lowpass Elliptic Filter	$f_{CUTOFF} = 500\text{kHz}$ or 1MHz
LTC1562/LTC1562-2	Universal 8th Order Active RC Filters	$f_{CUTOFF(MAX)} = 150\text{kHz}$ (LTC1562) $f_{CUTOFF(MAX)} = 300\text{kHz}$ (LTC1562-2)
LTC1563-2/LTC1563-3	4th Order Active RC Lowpass Filters	$f_{CUTOFF(MAX)} = 256\text{kHz}$
LTC1565-31	650kHz Continuous Time, Linear Phase Lowpass Filter	7th Order, Differential Inputs and Outputs
LTC1566-1	2.3MHz Continuous Time Lowpass Filter	7th Order, Differential Inputs and Outputs
LT1568	Very Low Noise 4th Order Filter Building Block	f_{CUTOFF} Up to 10MHz, Differential V_{OUT}
LTC1569-6/LTC1569-7	Self Clocked, 10th Order Linear Phase Lowpass Filters	$f_{CLK}/f_{CUTOFF} = 64/1$, $f_{CUTOFF(MAX)} = 64\text{kHz}$ (LTC1569-6) $f_{CLK}/f_{CUTOFF} = 32/1$, $f_{CUTOFF(MAX)} = 374\text{kHz}$ (LTC1569-7)

1567fa



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.